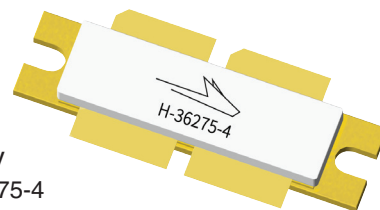


# PTVA035002EV

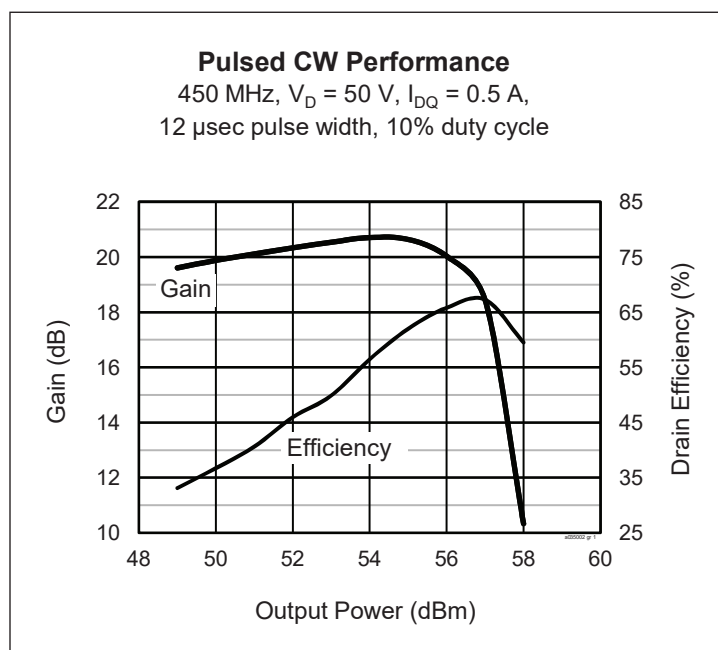
## Thermally-Enhanced High Power RF LDMOS FET 500 W, 50 V, 390 – 450 MHz

### Description

The PTVA035002EV LDMOS FET is designed for use in power amplifier applications in the 390 MHz to 450 MHz frequency band. Features include high gain and thermally-enhanced package with bolt-down flange. Manufactured with Wolfspeed's advanced LDMOS process, this device provides excellent thermal performance and superior reliability.



PTVA035002EV  
Package H-36275-4



### Features

- Unmatched input and output
- High gain and efficiency
- Integrated ESD protection
- Human Body Model Class 2 (per ANSI/ESDA/ JEDEC JS-001)
- Low thermal resistance
- Pb-free and RoHS-compliant
- Capable of withstanding a 13:1 load mismatch at 57 dBm under pulsed conditions: 12  $\mu$ sec pulse width, 10% duty cycle

### RF Characteristics

**Pulsed CW Class AB Characteristics** (not subject to production test, verified by design/characterization in Wolfspeed test fixture)

$V_{DD} = 50$  V,  $I_{DQ} = 0.5$  A,  $P_{OUT} = 500$  W,  $f = 450$  MHz, 12  $\mu$ sec pulse width, 10% duty cycle

Characteristic	Symbol	Min	Typ	Max	Unit
Gain	$G_{ps}$	—	18	—	dB
Drain Efficiency	$\eta_D$	—	64	—	%

All published data at  $T_{CASE} = 25^\circ\text{C}$  unless otherwise indicated

ESD: Electrostatic discharge sensitive device—observe handling precautions!

## RF Characteristics

### Pulsed CW Characteristics (tested in Wolfspeed test fixture)

$V_{DD} = 50\text{ V}$ ,  $V_{GS} = 2.9\text{ V}$ ,  $I_{DQ} = 0.0\text{ A}$ ,  $P_{OUT} = 500\text{ W}$ ,  $f = 450\text{ MHz}$ , 12  $\mu\text{sec}$  pulse width, 10% duty cycle

Characteristic	Symbol	Min	Typ	Max	Unit
Gain	$G_{ps}$	14.75	15.5	—	dB
Drain Efficiency	$\rho_D$	63	66	—	%

### DC Characteristics (each side)

Characteristic	Conditions	Symbol	Min	Typ	Max	Unit
Drain-Source Breakdown Voltage	$V_{GS} = 0\text{ V}$ , $I_{DS} = 10\text{ mA}$	$V_{(BR)DSS}$	105	—	—	V
Drain Leakage Current	$V_{DS} = 50\text{ V}$ , $V_{GS} = 0\text{ V}$	$I_{DSS}$	—	—	1.0	$\mu\text{A}$
	$V_{DS} = 105\text{ V}$ , $V_{GS} = 0\text{ V}$	$I_{DSS}$	—	—	10.0	$\mu\text{A}$
On-State Resistance	$V_{GS} = 10\text{ V}$ , $V_{DS} = 0.1\text{ V}$	$R_{DS(on)}$	—	0.1	—	$\Omega$
Operating Gate Voltage	$V_{DS} = 50\text{ V}$ , $I_{DQ} = 600\text{ mA}$	$V_{GS}$	—	3.70	—	V
Gate Leakage Current	$V_{GS} = 10\text{ V}$ , $V_{DS} = 0\text{ V}$	$I_{GSS}$	—	—	1.0	$\mu\text{A}$

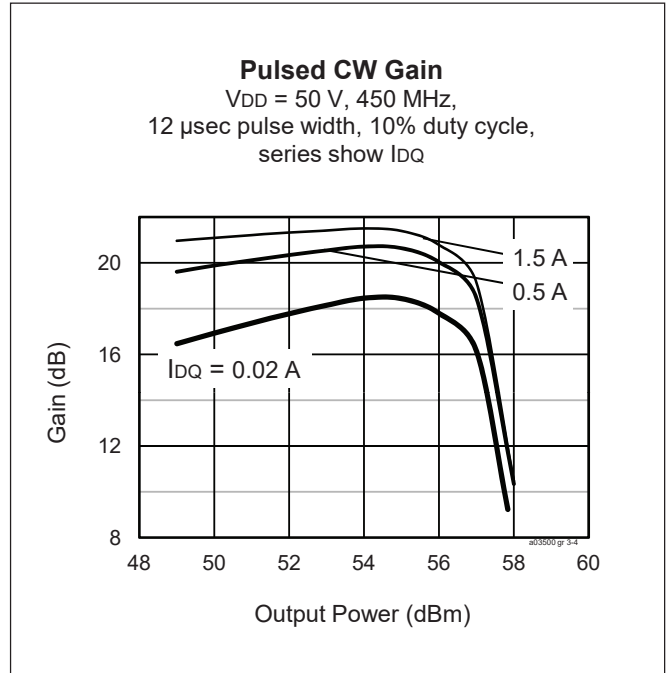
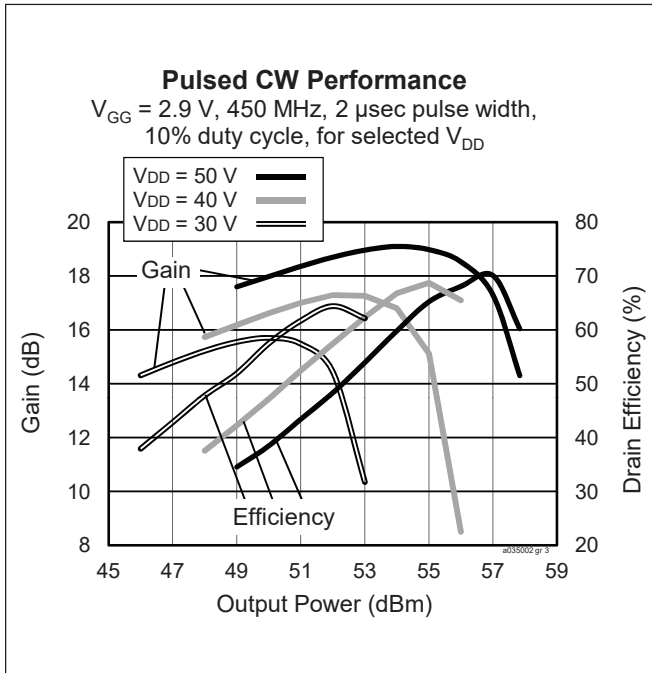
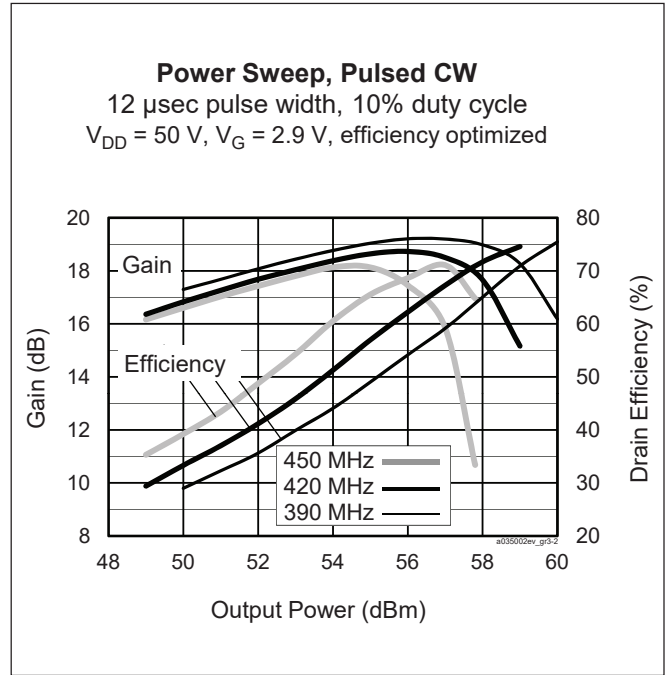
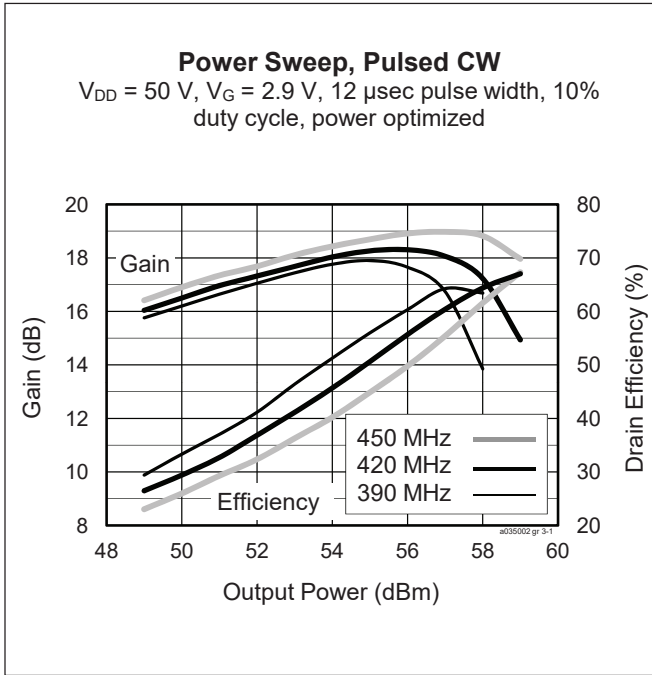
## Maximum Ratings

Parameter	Symbol	Value	Unit
Drain-Source Voltage	$V_{DSS}$	105	V
Gate-Source Voltage	$V_{GS}$	-6 to +12	V
Operating Voltage	$V_{DD}$	0 to +55	V
Junction Temperature	$T_J$	225	$^{\circ}\text{C}$
Storage Temperature Range	$T_{STG}$	-65 to +150	$^{\circ}\text{C}$
Thermal Resistance ( $T_{CASE} = 70^{\circ}\text{C}$ , 300 W CW)	$R_{\theta JC}$	0.20	$^{\circ}\text{C/W}$

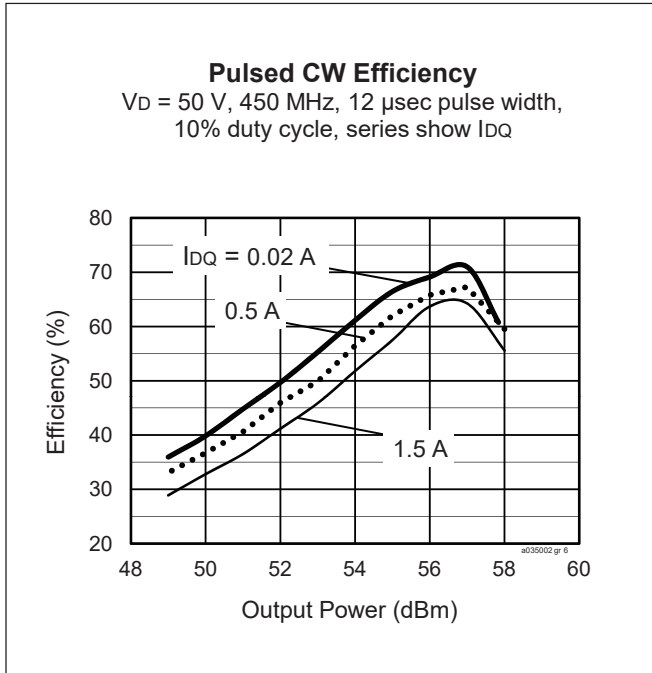
## Ordering Information

Type and Version	Order Code	Package Description	Shipping
PTVA035002EV V1 R0	PTVA035002EV-V1-R0	H-36275-4, bolt-down	Tape & Reel, 50pcs
PTVA035002EV V1 R250	PTVA035002EV-V1-R250	H-36275-4, bolt-down	Tape & Reel, 250pcs

**Typical Performance** (data taken in production test fixture)

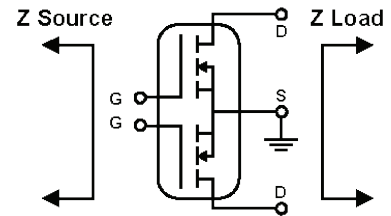


**Typical Performance** (cont.)

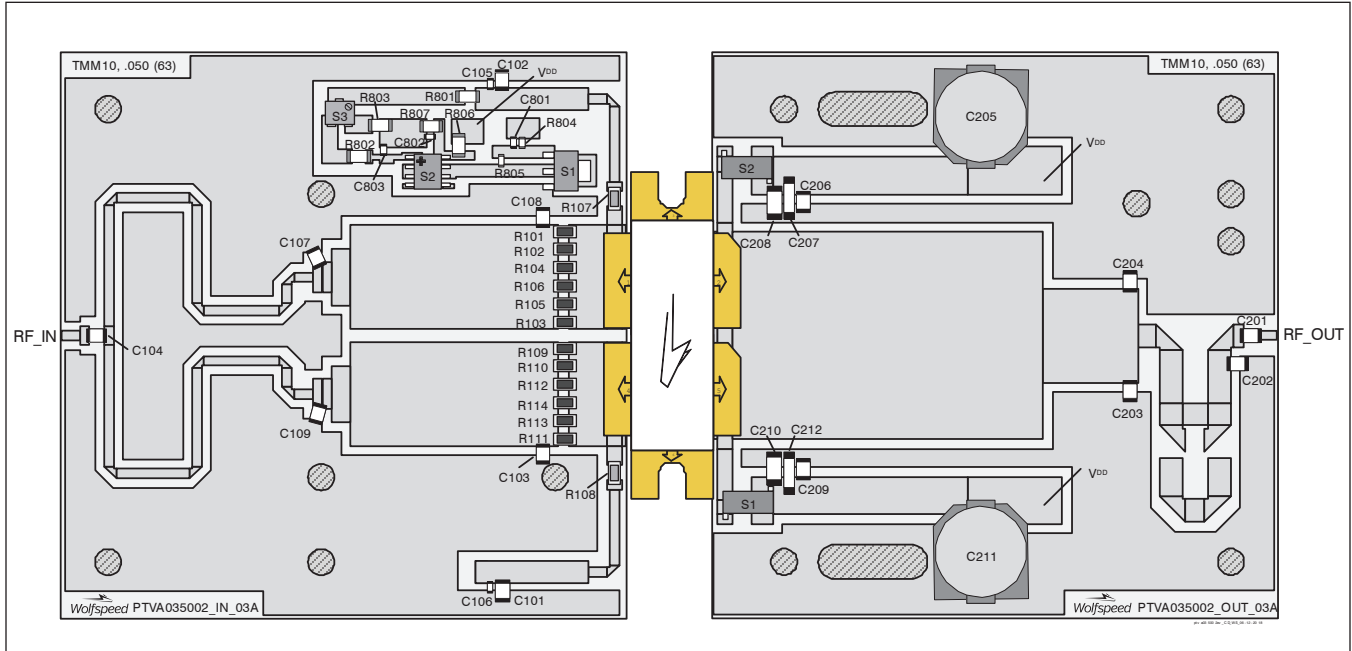


**Broadband Circuit Impedance**

Frequency MHz	Z Source $\Omega$		Z Load $\Omega$	
	R	jX	R	jX
390	1.28	-0.12	1.80	-2.22
405	1.35	0.18	1.86	-1.91
420	1.43	0.48	1.92	-1.62
435	1.54	0.76	1.98	-1.35
450	1.67	1.04	2.02	-1.11



### Reference Circuit, 390 – 450 MHz



Reference circuit assembly diagram (not to scale)\*

Find Gerber files for this test fixture on the WolfSpeed Web site at [www.wolfSpeed.com/RF](http://www.wolfSpeed.com/RF)

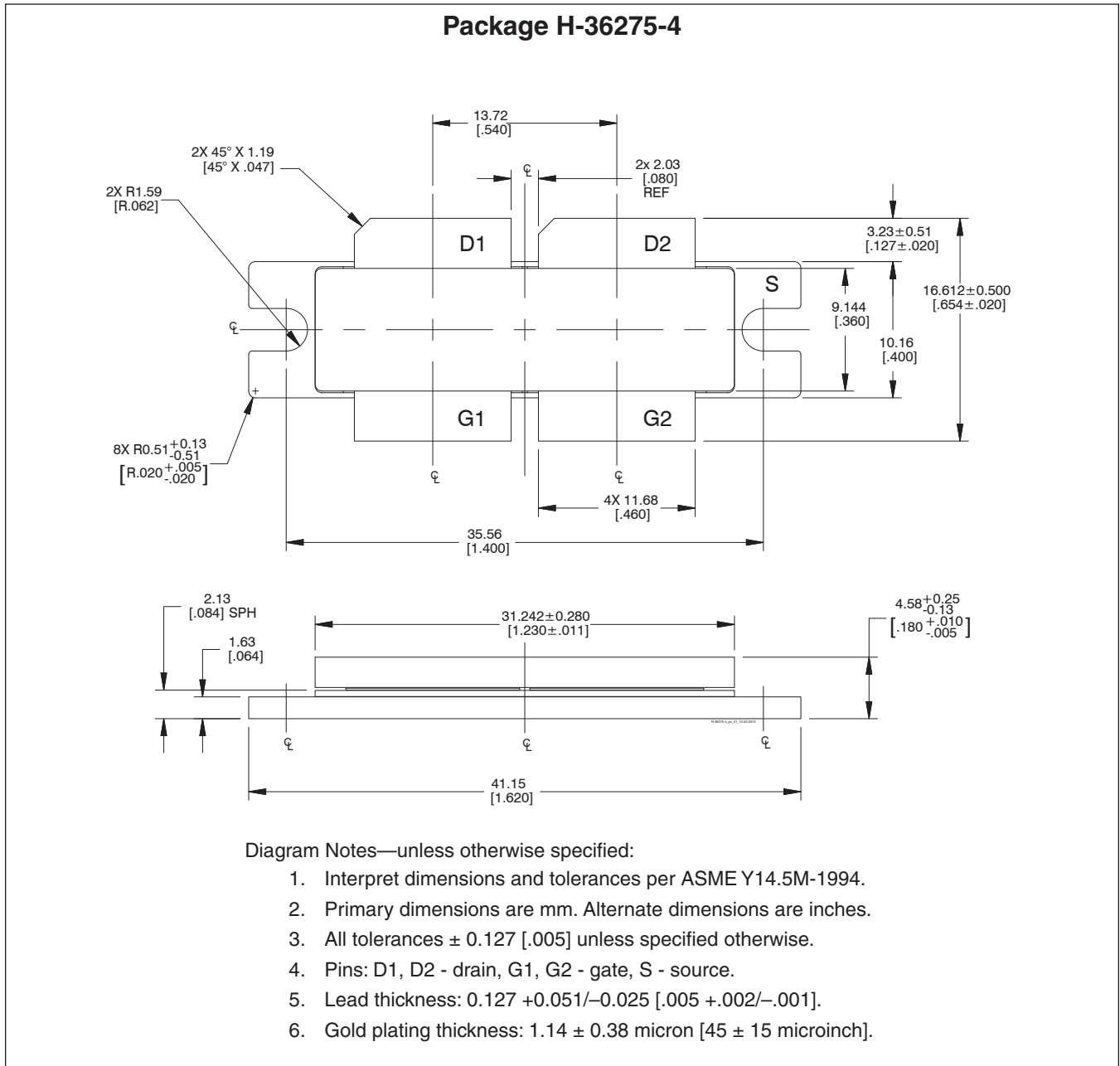
**Reference Circuit** (cont.)**Reference Circuit Assembly**

DUT	PTVA035002EV
Test Fixture Part No.	LTN/PTVA035002EV
PCB	Rogers TMM10, 1.27 mm [0.050"] thick, 2 oz. copper, $\epsilon_r = 9.2$

**Components Information**

Component	Description	Suggested Manufacturer	P/N
<b>Input</b>			
C101, C102, C104	Capacitor, 300 pF	ATC	ATC100B301KW200X
C103, C108	Capacitor, 20 pF	ATC	ATC100B200KW500X
C105, C106, C801, C802, C803	Capacitor, 1000 pF	Panasonic Electronic Components	ECJ-1VB1H102K
C107, C109	Capacitor, 6.2 pF	ATC	ATC100B6R2CT500X
R101, R102, R103, R104, R105, R106, R109, R110, R111, R112, R113, R114	Resistor, 5.6 $\Omega$	Panasonic Electronic Components	ERJ-8GEYJ5R6V
R107, R108	Resistor, 1000 $\Omega$	Panasonic Electronic Components	ERJ-8GEYJ102V
R801	Resistor, 100 $\Omega$	Panasonic Electronic Components	ERJ-8GEYJ101V
R802	Resistor, 2000 $\Omega$	Panasonic Electronic Components	ERJ-8GEYJ202V
R803	Resistor, 3600 $\Omega$	Panasonic Electronic Components	ERJ-8GEYJ362V
R804	Resistor, 1300 $\Omega$	Panasonic Electronic Components	ERJ-3GEYJ132V
R805	Resistor, 1200 $\Omega$	Panasonic Electronic Components	ERJ-3GEYJ122V
R806	Resistor, 2400 $\Omega$	Panasonic Electronic Components	ERJ-8GEYJ242V
R807	Resistor, 6200 $\Omega$	Panasonic Electronic Components	ERJ-8GEYJ622V
S1	Transistor	Infineon Technologies	BCP56
S2	Voltage regulator	Texas Instruments	LM7805
S3	Potentiometer	Bourns Inc.	3224W-1-202E
<b>Output</b>			
C201, C206, C209	Capacitor, 300 pF	ATC	ATC100B301KW200X
C202	Capacitor, 3 pF	ATC	ATC100B3R0CW500X
C203, C204	Capacitor, 4.3 pF	ATC	ATC100B4R3CW500X
C205, C211	Capacitor, 100 $\mu$ F	United Chemi-Con	EMVE101ARA101MKE0S
C207, C212	Capacitor, 10 $\mu$ F	TDK Corporation	C5750X7S2A106M230KB
C208, C210	Capacitor, 2.2 $\mu$ F	TDK Corporation	C4532X7R2A225K230KA
S1, S2	Inductor, 17.5 nH	Coilcraft	B06TGLB

Package Outline Specifications



## Revision History

Revision	Date	Data Sheet Type	Page	Subjects (major changes since last revision)
01	2010-10-07	Advance	All	Data Sheet reflects advance specification for product development
02	2010-12-09	Advance	1, 2	Added ESD and VSWR information and revised conditions of test, Revise conditions of test.
03	2011-04-28	Preliminary	All	Convert to Preliminary Data Sheet, adding performance graphs, substantiating some characterizations.
04	2012-02-24	Production	All 4 – 9	Convert to final Data Sheet for production-released product. Add impedance data, Add reference circuit
05.1	2016-04-19	Production	1, 2	Added ESD rating, updated ordering information
05.2	2016-06-08	Production	2	Updated ordering information to include R250
05.3	2017-02-02	Production	2	Added operating voltage and updated junction temperature
06	2018-06-12	Production	All	Converted to Wolfspeed Data Sheet

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## Notes

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